TPA SERIES

## FEATURES

- BIDIRECTIONAL CROWBAR PROTECTION.
- VOLTAGE RANGE: FROM 62 V TO 270 V.
- HOLDING CURRENT :
$I_{H}=150 \mathrm{~mA}$ min.
- REPETITIVE PEAK PULSE CURRENT : IPP $=50 \mathrm{~A}, 10 / 1000 \mu \mathrm{~s}$.


## DESCRIPTION

The TPA series are TRISIL devices especially designed for protecting sensitive telecommunication equipment against lightning and transient voltages induced by AC power lines. They are available in the DO-15 axial package.
TRISIL devices provide bidirectional protection by crowbar action. Their characteristic response to transient overvoltages makes them particularly suited to protect voltage sensitive telecommunication equipment.


## SCHEMATIC DIAGRAM



| COMPLIES WITH THE FOLLOWING STANDARDS: | Peak Surge Voltage (V) | Voltage Waveform ( $\mu \mathrm{s}$ ) | Current Waveform ( $\mu \mathrm{s}$ ) | Admissible Ipp <br> (A) | Necessary Resistor $(\Omega)$ |
| :---: | :---: | :---: | :---: | :---: | :---: |
| (CCITT) ITU-K20 | 1000 | 10/700 | 5/310 | 25 | - |
| (CCITT) ITU-K17 | 1500 | 10/700 | 5/310 | 38 | - |
| VDE0433 | 2000 | 10/700 | 5/310 | 50 | - |
| VDE0878 | 2000 | 1.2/50 | 1/20 | 50 | - |
| IEC-1000-4-5 | level 3 level 4 | $\begin{aligned} & 10 / 700 \\ & 1.2 / 50 \end{aligned}$ | $\begin{gathered} 5 / 310 \\ 8 / 20 \end{gathered}$ | $\begin{gathered} 50 \\ 100 \end{gathered}$ |  |
| FCC Part 68, lightning surge type A | $\begin{gathered} 1500 \\ 800 \end{gathered}$ | $\begin{aligned} & 10 / 160 \\ & 10 / 560 \end{aligned}$ | $\begin{aligned} & 10 / 160 \\ & 10 / 560 \end{aligned}$ | $\begin{aligned} & 75 \\ & 55 \\ & \hline \end{aligned}$ | $\begin{gathered} 12.5 \\ 6.5 \end{gathered}$ |
| FCC Part 68, lightning surge type B | 1000 | 9/720 | 5/320 | 25 | - |
| BELLCORE TR-NWT-001089 First level | $\begin{aligned} & 2500 \\ & 1000 \end{aligned}$ | $\begin{gathered} 2 / 10 \\ 10 / 1000 \end{gathered}$ | $\begin{gathered} 2 / 10 \\ 10 / 1000 \end{gathered}$ | $\begin{gathered} 150 \\ 50 \end{gathered}$ | $\begin{gathered} 11.5 \\ 10 \end{gathered}$ |
| BELLCORE TR-NWT-001089 Second level | 5000 | 2/10 | 2/10 | 150 | 11.5 |
| CNET I31-24 | 1000 | 0.5/700 | 0.8/310 | 25 | - |

TPA SERIES
ABSOLUTE MAXIMUM RATINGS ( $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ )

| Symbol | Parameter |  | Value | Unit |
| :---: | :--- | :---: | :---: | :---: |
| P | Power dissipation on infinite heatsink | $\mathrm{T}_{\mathrm{amb}}=50^{\circ} \mathrm{C}$ | 1.7 | W |
| IPP | Peak pulse current | $10 / 1000 \mu \mathrm{~s}$ <br> $8 / 20 \mu \mathrm{~s}$ | 50 <br> 100 | A |
|  |  | $\mathrm{tp}=20 \mathrm{~ms}$ | 30 | A |
| $\mathrm{I}_{\mathrm{TSM}}$ | Non repetitive surge peak on-state current | $\mathrm{tp}=20 \mathrm{~ms}$ | 9 | $\mathrm{~A}^{2} \mathrm{~s}$ |
| $\mathrm{I}^{2} \mathrm{t}$ | $\mathrm{I}^{2} \mathrm{t}$ value for fusing | $\mathrm{V}_{\mathrm{RM}}$ | 5 | $\mathrm{kV} / \mathrm{\mu s}$ |
| $\mathrm{dV} / \mathrm{dt}$ | Critical rate of rise of off-state voltage |  | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |
| $\mathrm{T}_{\text {stg }}$ | Storage temperature range |  |  |  |
| $\mathrm{T}_{\mathrm{j}}$ | Maximum junction temperature |  | ${ }^{\circ} \mathrm{C}$ |  |

## THERMAL RESISTANCES

| Symbol | Parameter | Value | Unit |
| :---: | :--- | :---: | :---: |
| $R_{\text {th }}(\mathrm{j}-\mathrm{l})$ | Junction to leads (L- lead $=10 \mathrm{~mm}$ ) | 60 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $R_{\text {th }}(\mathrm{j}-\mathrm{a})$ | Junction to ambient on printed circuit (Llead $=10 \mathrm{~mm})$ | 100 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## ELECTRICAL CHARACTERISTICS

( $\mathrm{T}_{\mathrm{amb}}=25^{\circ} \mathrm{C}$ )

| Symbol | Parameter |
| :---: | :--- |
| $\mathrm{V}_{\mathrm{RM}}$ | Stand-off voltage |
| $\mathrm{I}_{\mathrm{R}}$ | Leakage current at stand-off voltage |
| $\mathrm{V}_{\mathrm{R}}$ | Continuous Reverse voltage |
| $\mathrm{V}_{\mathrm{BR}}$ | Breakdown voltage |
| $\mathrm{V}_{\mathrm{BO}}$ | Breakover voltage |
| $\mathrm{I}_{\mathrm{H}}$ | Holding current |
| $\mathrm{I}_{\mathrm{BO}}$ | Breakover current |
| $\mathrm{I}_{\mathrm{PP}}$ | Peak pulse current |
| C | Capacitance |


| Type | $\begin{aligned} & \mathrm{I}_{\mathrm{RM}} @ \mathrm{~V}_{\mathrm{RM}} \\ & \max . \end{aligned}$ |  | $\mathrm{I}_{\mathrm{R}}^{\max } \text { @ } \mathrm{V}_{\mathbf{R}}$ |  | $\begin{aligned} & \mathrm{V}_{\mathrm{BO}} @ \mathrm{I}_{\mathrm{Bo}} \\ & \text { max. } \\ & \text { note } 2 \end{aligned}$ |  | $\mathrm{I}_{\mathrm{H}}$ <br> min. <br> note 3 <br> mA | C <br> max. <br> note 4 <br> pF |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | $\mu \mathrm{A}$ | v | $\mu \mathrm{A}$ | v | v | mA |  |  |
| TPA62 | 2 | 56 | 50 | 62 | 82 | 800 | 150 | 150 |
| TPA68 | 2 | 61 | 50 | 68 | 90 | 800 | 150 | 150 |
| TPA100 | 2 | 90 | 50 | 100 | 133 | 800 | 150 | 100 |
| TPA120 | 2 | 108 | 50 | 120 | 160 | 800 | 150 | 100 |
| TPA130 | 2 | 117 | 50 | 130 | 173 | 800 | 150 | 100 |
| TPA180 | 2 | 162 | 50 | 180 | 240 | 800 | 150 | 100 |
| TPA200 | 2 | 180 | 50 | 200 | 267 | 800 | 150 | 100 |
| TPA220 | 2 | 198 | 50 | 220 | 293 | 800 | 150 | 100 |
| TPA240 | 2 | 216 | 50 | 240 | 320 | 800 | 150 | 100 |
| TPA270 | 2 | 243 | 50 | 270 | 360 | 800 | 150 | 100 |

$\begin{array}{llll}\text { Note 1: } \\ \text { Note 3: measured at } V_{R} \text { guarantee } V_{B R m i n} \mid V_{R} & \text { See test circuit 2. }\end{array}$

TEST CIRCUIT 1 FOR $I_{\text {BO }}$ and $V_{B O}$ parameters :


TEST PROCEDURE :

- Pulse Test duration ( $\mathrm{tp}=20 \mathrm{~ms}$ ):
- For Bidirectional devices $=$ Switch K is closed
- For Unidirectional devices $=$ Switch K is open.
- Vout Selection
- Device with $\mathrm{V}_{\mathrm{BO}}<200$ Volt

$$
-V_{\text {OUT }}=250 \text { V }_{\text {RMS }}, R_{1}=140 \Omega .
$$

- Device with $\mathrm{V}_{\text {bo }} 200$ Volt
$-V_{\text {OUt }}=480$ V $_{\text {RMS }}, R_{2}=240 \Omega$.


## TEST CIRCUIT 2 for IH parameter.



This is a GO-NOGO Test which allows to confirm the holding current ( $l_{\mathrm{H}}$ ) level in a functional test circuit.

## TEST PROCEDURE :

- 1) Adjust the current level at the $I_{\mathrm{H}}$ value by short circuiting the AK of the D.U.T.

2) Fire the D.U.T with a surge Current : $\operatorname{Ipp}=10 \mathrm{~A}, 10 / 1000 \mu \mathrm{~s}$.
3) The D.U.T will come back off-state within 50 ms max.

Fig. 1: Non repetitive surge peak on-state current versus overload duration (Tj initial $=25^{\circ} \mathrm{C}$ ).


Fig. 3: Relative variation of junction capacitance versus reverse applied voltage (typical values). Note: For $V_{R M}$ upper than 56 V , the curve is extrapolated (dotted line).

C[VR]/C[VR=1V]


Fig. 2: Relative variation of holding current versus junction temperature.
$\mathrm{IH}[\mathrm{Tj}] / \mathrm{IH}\left[\mathrm{Tj}=25^{\circ} \mathrm{C}\right]$


Fig. 4: On-state current versus on-state voltage (typical values).


Fig. 5: Transient thermal impedance junction to ambient versus pulse duration (for FR4 PC Board with $\left.T_{\text {lead }}=10 \mathrm{~mm}\right)$.

Zth(j-a)( $\left.{ }^{\circ} \mathrm{CW}\right)$


ORDER CODE


MARKING: Logo, Date Code, Part Number.

PACKAGE MECHANICAL DATA
DO-15 (Plastic)


| REF. | DIMENSIONS |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
|  | Millimeters |  | Inches |  |
|  | Min. | Max. | Min. | Max. |
| A | 6.05 | 6.75 | 0.238 | 0.266 |
| B | 2.95 | 3.53 | 0.116 | 0.139 |
| C | 26 | 31 | 1.024 | 1.220 |
| D | 0.71 | 0.88 | 0.028 | 0.035 |

## Weight: 0.4 g

Packaging : Standard packaging is in tape and reel.

Information furnished is believed to be accurate and reliable. However, STMicroelectronics assumes no responsibility for the consequences of use of such information nor for any infringement of patents or other rights of third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of STMicroelectronics. Specifications mentioned in this publication are subject to change without notice. This publication supersedes and replaces all information previously supplied.
STMicroelectronics products are not authorized for use as critical components in life support devices or systems without express written approval of STMicroelectronics.

The ST logo is a registered trademark of STMicroelectronics
© 2003 STMicroelectronics - Printed in Italy - All rights reserved.
STMicroelectronics GROUP OF COMPANIES
Australia - Brazil - Canada - China - Finland - France - Germany
Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore Spain - Sweden - Switzerland - United Kingdom - United States.
http://www.st.com

